

# isc N-Channel Mosfet Transistor

## STF20NM60D

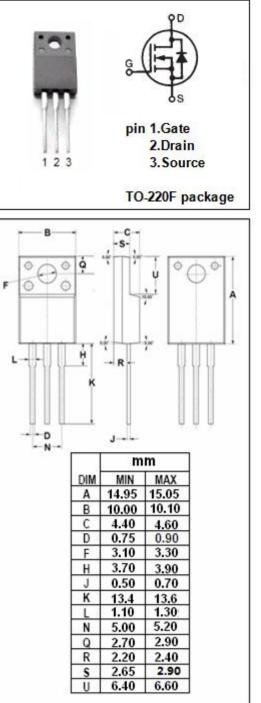
- FEATURES
- Drain Current I\_D= 20A@ T\_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-
  - : V<sub>DSS</sub>= 600V(Min)
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

Switching applications

## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	600	V				
V <sub>GS</sub>	Gate-Source Voltage	±30	V				
I <sub>D</sub>	Drain Current-continuous@ T <sub>C</sub> =25℃	20	А				
I <sub>DM</sub>	Pulse Drain Current	80	А				
P <sub>tot</sub>	Total Dissipation@T <sub>C</sub> =25℃	45	W				
Tj	Max. Operating Junction Temperature	-65~150	°C				
T <sub>stg</sub>	Storage Temperature Range	-65~150	°C				
• THERMAL CHARACTERISTICS							
SYMBOL	PARAMETER	МАХ	UNIT				



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Thermal Resistance, Junction to Case

2.8

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°C/W

R<sub>th j-c</sub>



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## **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{C}}\text{=}25\,^\circ\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =250µA	3		5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 10A			290	mΩ
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = Max rating			1	- μΑ
		V <sub>DS</sub> = Max rating; T <sub>C</sub> =125℃			10	
V <sub>SD</sub>	Diode Forward On-Voltage	I <sub>S</sub> = 20A ;V <sub>GS</sub> = 0			1.5	V

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